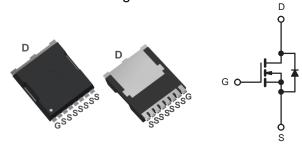


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N-Channel 80 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (mΩ) TYP.	I _D (A)	Q _g (TYP.)	
80	0.85 at V _{GS} = 10 V	360	185 nC	

TOLL Pin Configuration



N-Channel MOSFET

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS tested

APPLICATIONS

- Power supplies:
 - Uninterruptible power supplies
 - AC/DC switch-mode power supplies - Lighting
- Synchronous rectification
- DC/DC converter
- Motor drive switch
- DC/AC inverter
- Battery management

ABSOLUTE MAXIMUM RATINGS	$(T_C = 25 \ ^{\circ}C, \text{ unless othe})$	rwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	80	M	
Gate-Source Voltage		V _{GS}	± 20	V	
	T _C = 25 °C		360		
Continuous Drain Current ($T_J = 150 \ ^{\circ}C$)	T _C = 100 °C	I _D	215		
Pulsed Drain Current (t = 100 μs)		I _{DM}	1360	A	
Avalanche Current	L = 0.1 mH	I _{AS}	345		
Single Avalanche Energy ^a		E _{AS}	2850	mJ	
Maximum Dawar Dissinction a	T _C = 25 °C	р	420 ^b	w	
Maximum Power Dissipation ^a	T _C = 100 °C	- P _D -	386 ^b	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient (PCB Mount) ^c	t ≤ 10 s	R _{thJA}	10	°C/W	
Junction-to-Case (Drain)	Steady State	R _{thJC}	0.25		

Notes

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR4 material).





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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	V_{GS} = 0 V, I_D = 250 μ A	80	-	-	- V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\;\mu A$	1.5	-	3.5	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
		$V_{DS} = 80 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 64 V, V_{GS} = 0 V, T_J = 85 $^\circ C$	-	-	30	- μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge$ 10 V, V_{GS} = 10 V	360	-	-	А
Drain-Source On-State Resistance ^a	Brach	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 100 \text{ A}$	-	0.85	1.1	mΩ
	R _{DS(on)}	$V_{GS} = 6 V, I_D = 75 A$	-	1.2	1.6	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 100 \text{ A}$	-	255	-	S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 40 V, f = 1 MHz	-	15670	-	pF
Output Capacitance	C _{oss}		-	3893	-	
Reverse Transfer Capacitance	C _{rss}		-	64	-	
Total Gate Charge ^c	Qg		-	185	-	nC
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 40 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 100 \text{ A}$	-	58	-	
Gate-Drain Charge ^c	Q _{gd}		-	42	-	
Gate Resistance	R _g	f = 1 MHz	-	1.8	-	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	38	-	
Rise Time ^c	t _r	V_{DD} = 40 V, I_D =100 A, R_g = 6 Ω	-	45	-	20
Turn-Off Delay Time ^c	t _{d(off)}	V _{GEN} = 10 V	-	62	-	ns
Fall Time ^c	t _f		-	32	-	
Drain-Source Body Diode Ratings and	Characterist	cs ^b (T _C = 25 °C)				
Continuous Source-Drain Diode Current	۱ _S	T _C = 25 °C	-	-	360	А
Pulsed Current (t = 100 µs)	I _{SM}		-	-	1360	А
Forward Voltage ^a	V _{SD}	$I_{F} = 1 \text{ A}, V_{GS} = 0 \text{ V}$	-	-	1	V
Reverse Recovery Time	t _{rr}		-	178	-	ns
Reverse Recovery Charge	Q _{rr}	I _F = 100 A, di/dt = 100 A/μs	-	445	-	nC

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%.$

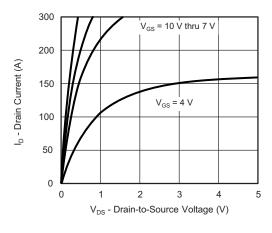
b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

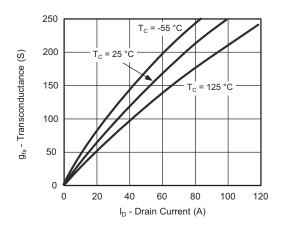
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



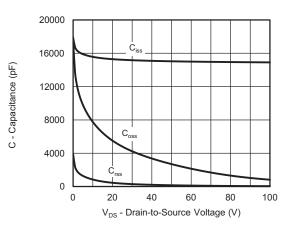
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



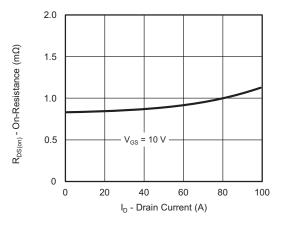
Output Characteristics



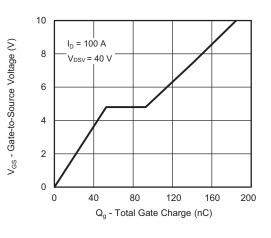
Transconductance



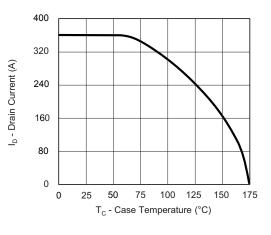
Capacitance



On-Resistance vs. Drain Current



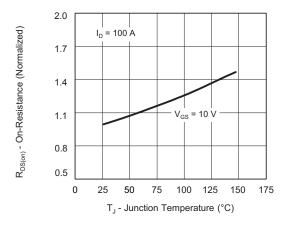
Gate Charge



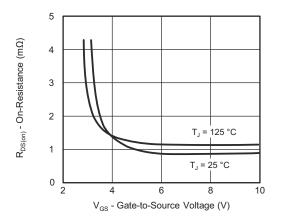
Current De-Rating



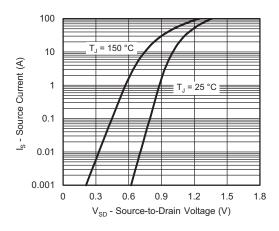
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



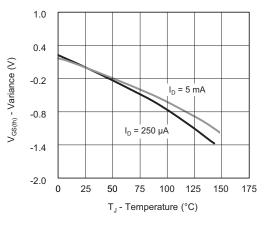
On-Resistance vs. Junction Temperature



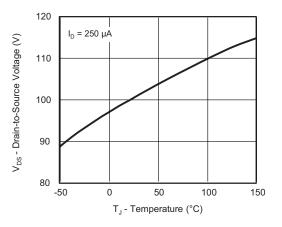
On-Resistance vs. Gate-to-Source Voltage



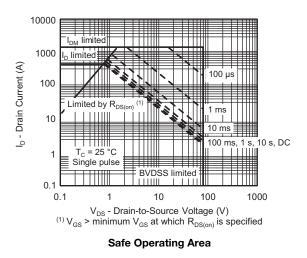
Source Drain Diode Forward Voltage



Threshold Voltage

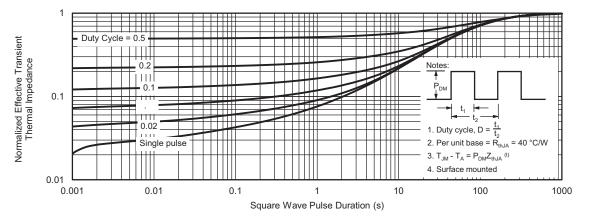


Drain Source Breakdown vs. Junction Temperature





THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



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